

DIGITRON SEMICONDUCTORS

UF110-UF120

ULTRA FAST RECOVERY RECTIFIERS

ELECTRICAL CHARACTERISTICS

Characteristics	Symbol	UF110	UF115	UF120	Test Conditions
Working peak reverse voltage	V_{RWM}	100V	150V	200V	
Repetitive peak reverse voltage	V_{RRM}	100V	150V	200V	
Average forward current	$I_{F(AV)}$	1.0A			$T_L = 135^\circ\text{C}$, square wave, $R_{eJL} = 15^\circ\text{C}/\text{W}$, $L = \frac{1}{4}\text{"}$
Maximum surge current	I_{FSM}	35A			8.3ms, half-sine, $T_J = 175^\circ\text{C}$
Maximum peak forward voltage	V_{FM}	0.75V			$I_{FM} = 0.1\text{A}$, $T_J = 25^\circ\text{C}$ *
Maximum peak forward voltage	V_{FM}	0.95V			$I_{FM} = 1.0\text{A}$, $T_J = 25^\circ\text{C}$ *
Maximum reverse recovery time	t_{rr}	30ns			1/2A, 1A, 1/4A, $T_J = 25^\circ\text{C}$
Maximum peak reverse current	I_{RM}	5μA			V_{RRM} , $T_J = 25^\circ\text{C}$
Typical junction capacitance	C_J	10pF			$V_R = 10\text{V}$, $T_J = 25^\circ\text{C}$

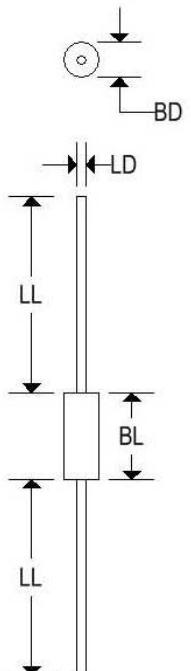
*Pulse test: pulse width 300μsec, duty cycle 2%

THERMAL CHARACTERISTICS

Characteristics	Symbol	Test Conditions
Storage temperature range	T_{stg}	-55° to 175°C
Operating junction temperature range	T_J	-55° to 175°C
Maximum thermal resistance, $L = \frac{1}{4}\text{"}$	R_{eJL}	15°C/W junction to lead

MECHANICAL CHARACTERISTICS

Case	DO-41
Marking	Body painted, alpha numeric
Polarity	Cathode band



	DO-41			
	Inches		Millimeters	
	Min	Max	Min	Max
BD	-	0.107	-	2.720
BL	-	0.205	-	5.207
LD	0.028	0.034	0.711	0.864
LL	1.000	-	25.400	-

Available Non-RoHS (standard) or RoHS compliant (add PBF suffix).

Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.

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Figure 1
Typical Forward Characteristics

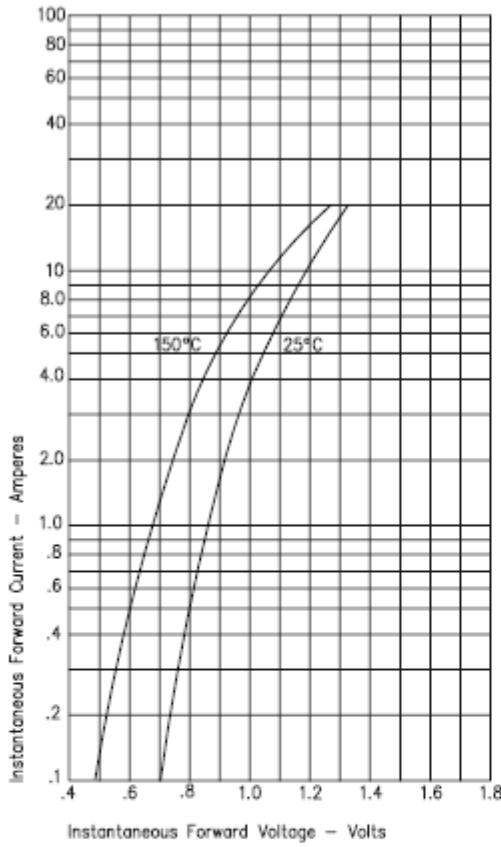


Figure 2
Typical Reverse Characteristics

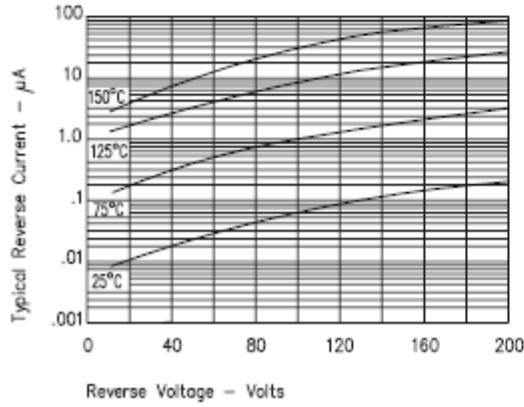


Figure 3
Typical Junction Capacitance

